NSN 5961-01-061-9859



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-061-9859 **Inclosure Material:** Metal **Overall Length:** 0.085 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Function For Which Designed:** Switching **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Pnp **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.090 inches and 0.110 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -30.0 collector to base voltage/static/emitter open and -20.0 collector to emitter voltage/static/base open and -30.0 emitter to base voltage, static, collector open and -20.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:**

400.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Test Data Document:

88818-a532a063 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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